



DMPH6050SFGQ

60V P-CHANNEL +175°C MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C		
-60V	$50m\Omega$ @ $V_{GS} = -10V$	-18A		
-007	$70m\Omega @ V_{GS} = -4.5V$	-15A		

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Backlighting
- Power Management Functions
- DC-DC Converters

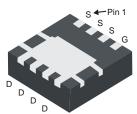
Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- Low R_{DS(ON)} ensures on state losses are minimized
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

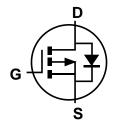
Mechanical Data

- Case: PowerDI[®]3333-8
- Case Material: Molded Plastic, "Green" Molding Compound;
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (23)
- Weight: 0.072 grams (Approximate)

PowerDI3333-8







Equivalent Circuit

Ordering Information (Note 5)

Bottom View

Part Number	Case	Packaging
DMPH6050SFGQ-7	PowerDI3333-8	2,000/Tape & Reel
DMPH6050SFGQ-13	PowerDI3333-8	3,000/Tape & Reel

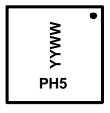
Top View

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

PowerDI3333-8



PH5= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 17 = 2017) WW = Week Code (01 to 53)

PowerDI is a registered trademark of Diodes Incorporated.



Maximum Ratings (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V_{DSS}	-60	V		
Gate-Source Voltage			V_{GSS}	±20	V
Continuous Drain Current (Note 7) V _{GS} = -10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +100^{\circ}C$	I _D	-6.1 -4.2	А
Continuous Drain Current (Note 8) V _{GS} = -10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I _D	-18 -12	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-32	Α		
Maximum Continuous Body Diode Forward Current (Is	-2	Α		
Pulsed Body Diode Forward Current (10µs Pulse, Du	I _{SM}	-32	Α		
Avalanche Current (Note 9) L = 0.1mH	I _{AS}	-24.8	Α		
Avalanche Energy (Note 9) L = 0.1mH	Eas	30.8	mJ		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)		P_{D}	1.2	W
Thermal Begintance, Junction to Ambient (Note 6)	Steady state	6	125	°C/W
Thermal Resistance, Junction to Ambient (Note 6)		$R_{\theta JA}$	85	C/VV
Total Power Dissipation (Note 7)		P_{D}	2.8	W
Thermal Resistance, Junction to Ambient (Note 7) Steady s t<10s		$R_{ heta JA}$	54	°C/W
			37	
Thermal Resistance, Junction to Case (Note 8)		$R_{ heta JC}$	6	
Operating and Storage Temperature Range		$T_{J_1}T_{STG}$	-55 to +175	°C

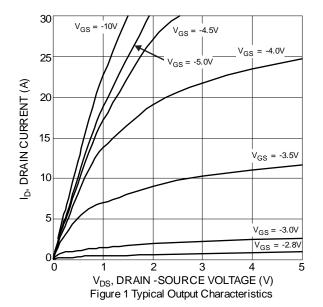
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

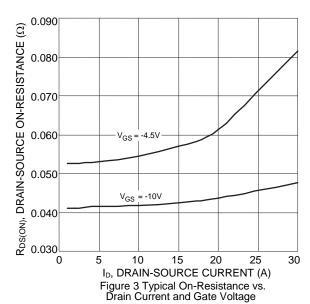
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 10)							
Drain-Source Breakdown Voltage	BV _{DSS}	-60	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_	_	-1	μΑ	$V_{DS} = -60V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 10)							
Gate Threshold Voltage	V _{GS(TH)}	-1	_	-3	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance		_	41	50	mΩ	$V_{GS} = -10V, I_{D} = -7A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	52	70	11122	$V_{GS} = -4.5V, I_D = -7A$	
Diode Forward Voltage	V_{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 11)							
Input Capacitance	C _{iss}	_	1293	_	pF	.,	
Output Capacitance	Coss	_	86.3	-	pF	$V_{DS} = -30V, V_{GS} = 0V,$ - f = 1MHz	
Reverse Transfer Capacitance	C _{rss}	_	64.7	l	рF	11 = 11011112	
Gate Resistance	R_g	_	12	-	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Q_g	_	11.9	_	nC	V _{DS} = -30V, I _D = -5A	
Total Gate Charge (V _{GS} = -10V)	Qg	_	24.1	_	nC		
Gate-Source Charge	Q _{gs}	_	3.6	_	nC		
Gate-Drain Charge	Q_{gd}	_	5.7	_	nC		
Turn-On Delay Time	t _{D(ON)}	_	4.3	_	ns	$V_{DS} = -30V, V_{GS} = -10V,$ $R_G = 3\Omega, I_D = -5A$	
Turn-On Rise Time	t _R	_	6.3	_	ns		
Turn-Off Delay Time	t _{D(OFF)}	_	46.7	_	ns		
Turn-Off Fall Time	t _F	_	25.3	_	ns		
Body Diode Reverse Recovery Time	t _{RR}	_	13.6		ns	I _F = -5A, di/dt = 100A/μs	
Body Diode Reverse Recovery Charge	Q _{RR}	_	7.4	_	nC		

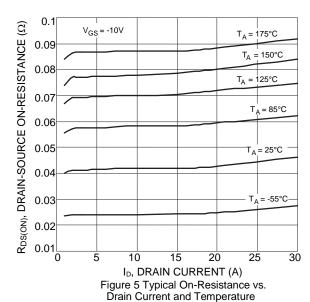
- 6. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 7. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

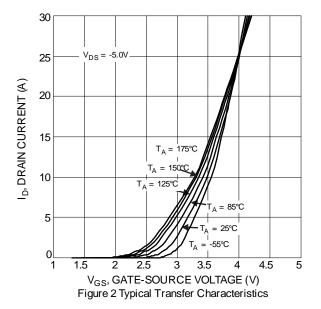
 8. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 9. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.
- 10. Short duration pulse test used to minimize self-heating effect.
- 11. Guaranteed by design. Not subject to product testing.

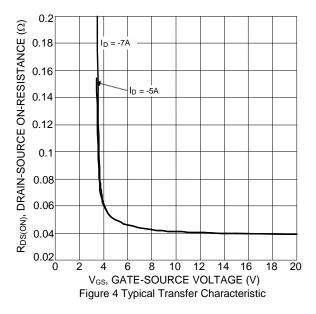












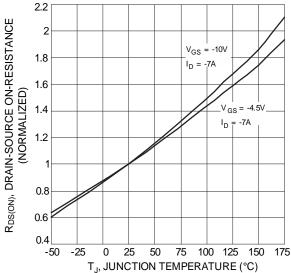


Figure 6 On-Resistance Variation with Temperature



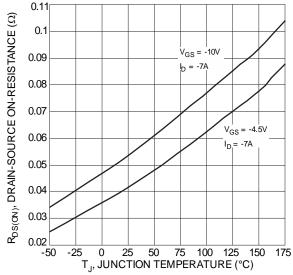


Figure 7 On-Resistance Variation with Temperature

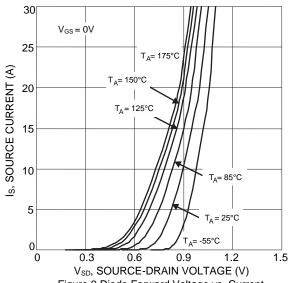
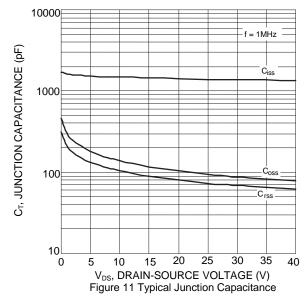
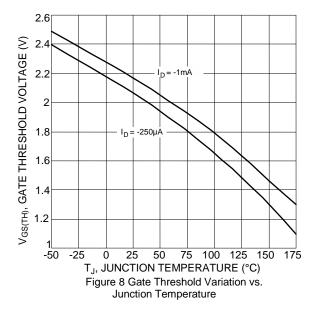
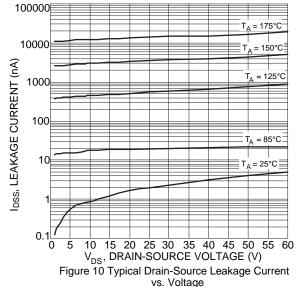


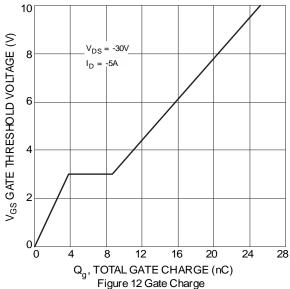
Figure 9 Diode Forward Voltage vs. Current



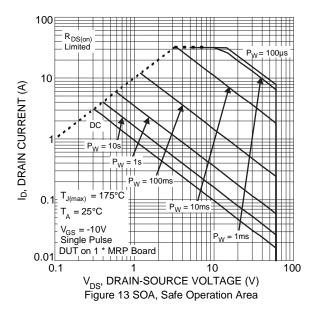




vs. Voltage







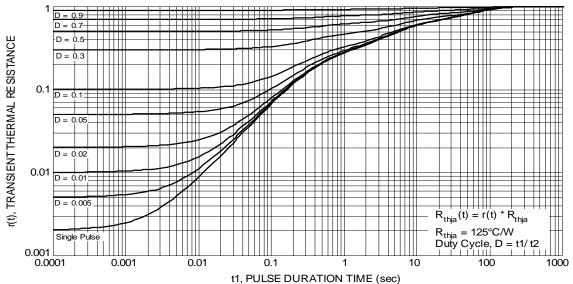


Figure 14 Transient Thermal Resistance

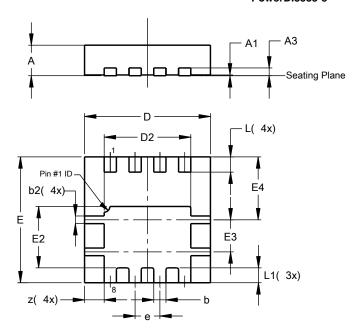
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Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

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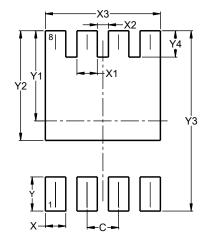


PowerDI3333-8					
Dim	Min	Max	Тур		
Α	0.75	0.85	0.80		
A1	0.00	0.05	0.02		
A3	-	_	0.203		
b	0.27	0.37	0.32		
b2	0.15	0.25	0.20		
D	3.25	3.35	3.30		
D2	2.22	2.32	2.27		
E	3.25	3.35	3.30		
E2	1.56	1.66	1.61		
E3	0.79	0.89	0.84		
E4	1.60	1.70	1.65		
е	-	_	0.65		
L	0.35	0.45	0.40		
L1	_	_	0.39		
Z	_	_	0.515		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

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Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
Х3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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